



1.0A SCHOTTKY BARRIER RECTIFIER

Product Summary

3120AF	/B130AF	/B140AF
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V _{RRM} (V)	I _O (A)	V _{F(MAX)} (V) @ +25°C	I _{R(MAX)} (mA) @ +25°C
20	1	0.5	0.1
30	1	0.5	0.1
40	1	0.5	0.2

Description and Applications

The Schottky rectifier providing low V_F and excellent reverse leakage stability at high temperatures, this device is ideal for use in general rectification applications such as:

- Boost Diode
- Blocking Diode
- · Recirculating Diode

Features and Benefits

- Reduced Low Forward Voltage Drop (V_F); Better Efficiency and Cooler Operation
- Reduced High-Temperature Reverse Leakage; Increased Reliability against Thermal Runaway Failure in High Temperature Operation
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SMAF
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (€3)
- Polarity: Cathode Band
- Weight: 0.036 grams (Approximate)

SMAF



Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
B120AF-13	SMAF	10,000/Tape & Reel
B130AF-13	SMAF	10,000/Tape & Reel
B140AF-13	SMAF	10,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



B120AF-B140AF
Document number: DS39504 Rev. 2 - 2



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	B120AF	B130AF	B140AF	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	20	30	40	>
Average Rectified Output Current	Io		1		Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}		30		А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	95	°C/W
Typical Thermal Resistance Junction to Case (Note 5)	R ₀ JC	45	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop	V _F	_	0.455 0.40	0.50 —	V	$I_F = 1A$, $T_J = +25$ °C $I_F = 1A$, $T_J = +125$ °C
B120 Leakage Current (Note 6) B130 B140	AF I _R	_ _ _ _	0.005 0.006 0.010 6.0	0.10 0.10 0.20	mA	V _R = 20V, T _J = +25°C V _R = 30V, T _J = +25°C V _R = 40V, T _J = +25°C V _R = 40V, T _J = +125°C
Typical Capacitance	C _T	_	50	_	pF	$V_R = 4.0V$, $f = 1MHz$

Notes:

- 5. Device mounted on FR-4 substrate, 0.4" x 0.5", 2oz, single-sided, PC boards with 0.2" x 0.25" copper pad. 6. Short duration pulse test used to minimize self-heating effect.



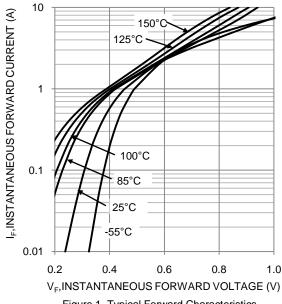
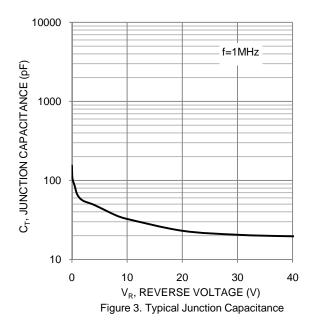


Figure 1. Typical Forward Characteristics



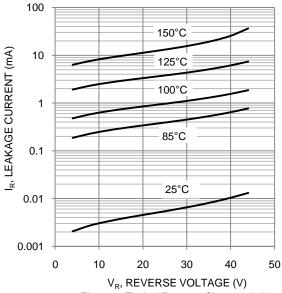


Figure 2. Typical Reverse Characteristics

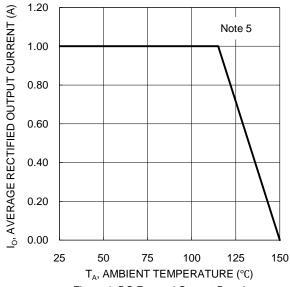


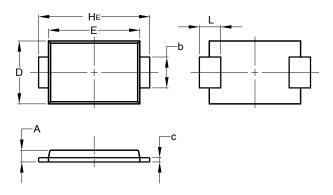
Figure 4. DC Forward Current Derating



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SMAF

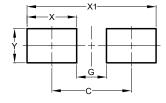


SMAF						
Dim	Min Max					
Α	0.90	1.10				
b	1.25	1.65				
С	0.10	0.40				
D	2.25	2.95				
Е	3.95 4.60					
HE	4.80 5.60					
L	0.50	1.50				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SMAF



Dimensions	Value (in mm)
С	4.00
G	1.50
Х	2.50
X1	6.50
Υ	1.70



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